

# PDTC124ET

50 V, 100 mA NPN resistor-equipped transistor; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$ 

13 October 2022

**Product data sheet** 

# 1. General description

NPN Resistor-Equipped Transistor (RET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

PNP complement: PDTA124ET

## 2. Features and benefits

- 100 mA output current capability
- · Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

# 3. Applications

- Digital application in automotive and industrial segments
- Cost-saving alternative for BC847 series in digital applications
- · Controlling IC inputs
- Switching loads

# 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	50	V
Io	output current			-	-	100	mA
R1	bias resistor 1 (input)		[1]	15.4	22	28.6	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	

[1] See "Section 11: Test information" for resistor calculation and test conditions.



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# 5. Pinning information

#### **Table 2. Pinning information**

1 I 2 GN 3 O		input (base) ground (emitter)	3	
	SND !	ground (emitter)		
2		• ,		↓ R1 ↓ ✓ I
3 0	)	output (collector)	SOT23	GND R2

# 6. Ordering information

## **Table 3. Ordering information**

Type number Package						
	Name	Description	Version			
PDTC124ET	SOT23	plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23			

# 7. Marking

## Table 4. Marking codes

Type number	Marking code[1]
PDTC124ET	<b>%17</b>

[1] % = placeholder for manufacturing site code

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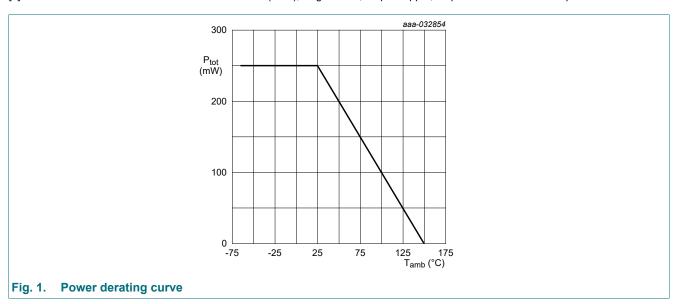
# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter		-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	10	V
VI	input voltage	positive		-	40	V
		negative		-	-10	V
Io	output current			-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	250	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.



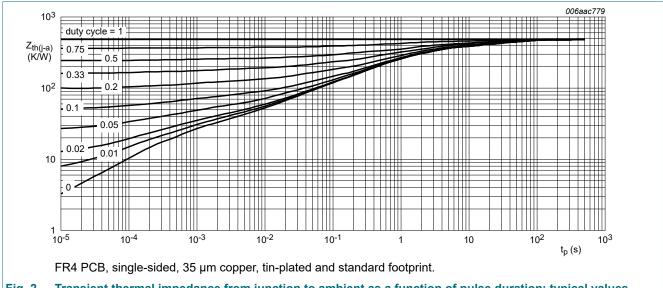
50 V, 100 mA NPN resistor-equipped transistor; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$ 

# 9. Thermal characteristics

#### **Table 6. Thermal characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
uiu-a)	thermal resistance from junction to ambient	in free air	[1]	-	-	500	K/W

[1] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint.



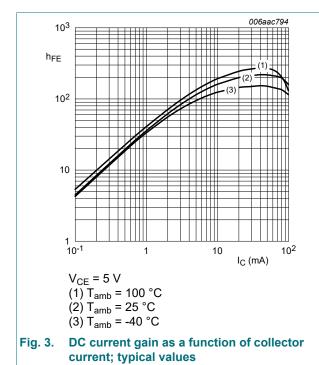
Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

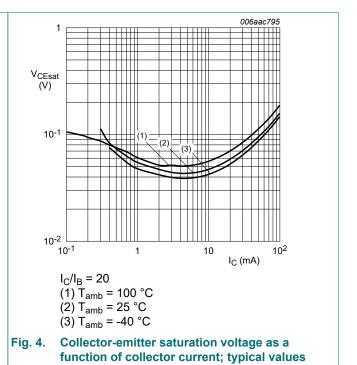
# 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$		50	-	-	V
V <sub>(BR)CEO</sub>	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		50	-	-	V
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	100	nA
I <sub>CEO</sub>	collector-emitter cut-off	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	100	nA
	current	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	180	μΑ
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 5 mA; T <sub>amb</sub> = 25 °C		60	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		-	-	100	mV
V <sub>I(off)</sub>	off-state input voltage	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 100 μA; T <sub>amb</sub> = 25 °C		-	1.1	0.8	V
V <sub>I(on)</sub>	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 5 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		2.5	1.7	-	V
R1	bias resistor 1 (input)		[1]	15.4	22	28.6	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	
C <sub>c</sub>	collector capacitance	$V_{CB}$ = 10 V; $I_{E}$ = 0 A; $i_{e}$ = 0 A; f = 1 MHz; $T_{amb}$ = 25 °C		-	-	2.5	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = 5 V; $I_{C}$ = 10 mA; f = 100 MHz; $T_{amb}$ = 25 °C	[2]	-	230	-	MHz

- [1] See "Section 11: Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor.





## 50 V, 100 mA NPN resistor-equipped transistor; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$

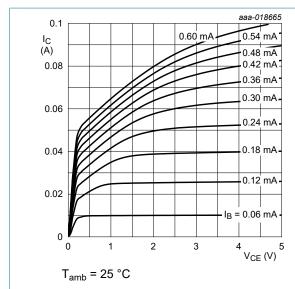
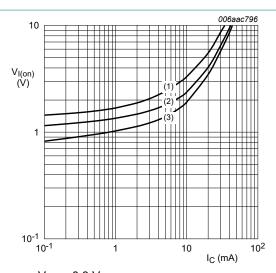


Fig. 5. Collector current as a function of collectoremitter voltage; typical values

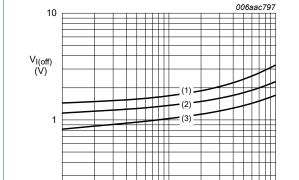


V<sub>CE</sub> = 0.3 V (1) T<sub>amb</sub> = -40 °C (2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = 100 °C

T<sub>amb</sub> = 25 °C

Fig. 6.

On-state input voltage as a function of collector



V<sub>CE</sub> = 5 V (1) T<sub>amb</sub> = -40 °C (2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = 100 °C

10<sup>-1</sup> 10<sup>-1</sup>

Fig. 7. Off-state input voltage as a function of collector current; typical values

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I<sub>C</sub> (mA)

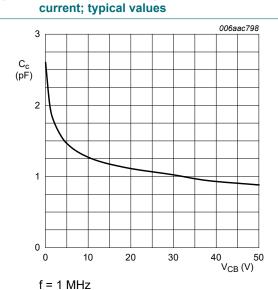
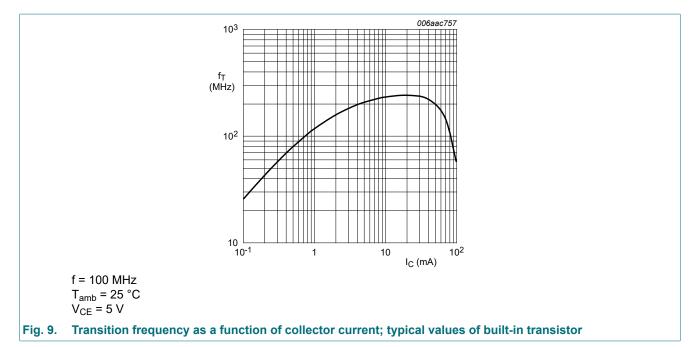


Fig. 8. Collector capacitance as a function of collectorbase voltage; typical values

# 50 V, 100 mA NPN resistor-equipped transistor; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$



50 V, 100 mA NPN resistor-equipped transistor; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$ 

# 11. Test information

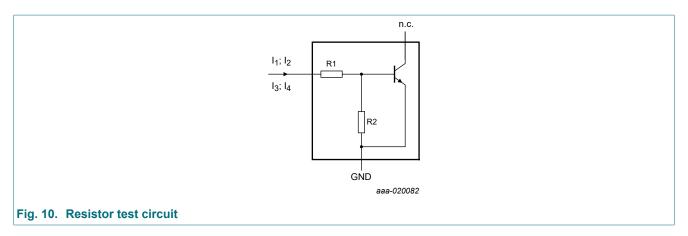
#### **Resistor calculation**

• Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$



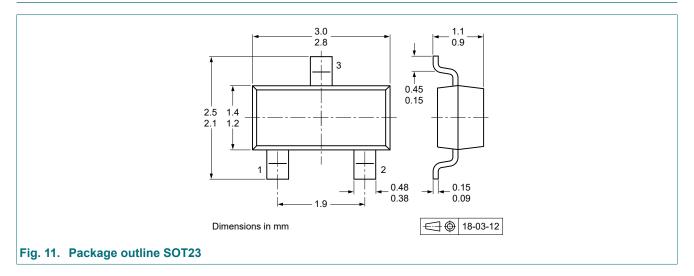
## **Resistor test conditions**

**Table 8. Resistor test conditions** 

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions				
			I <sub>1</sub>	l <sub>2</sub>	l <sub>3</sub>	14	
PDTC124ET	22	22	150 μΑ	230 μΑ	-150 μA	-230 µA	

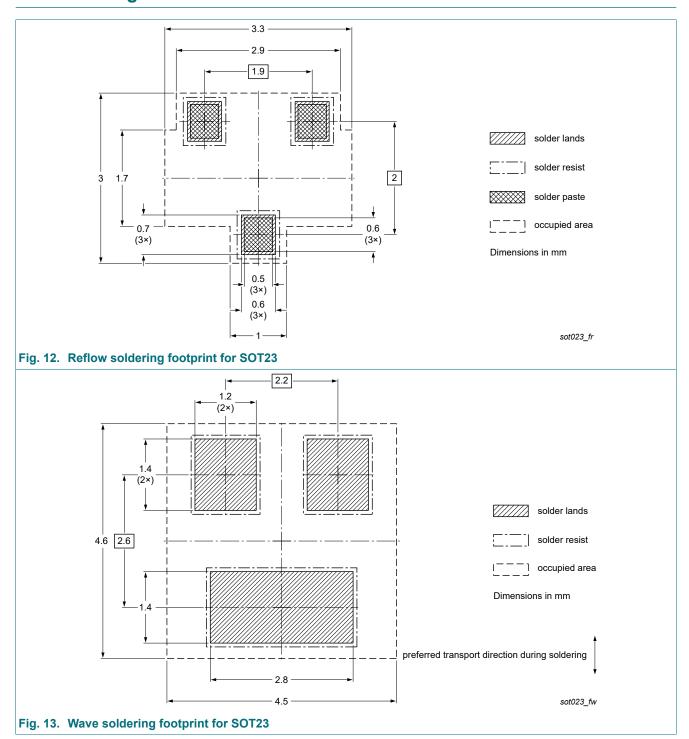
50 V, 100 mA NPN resistor-equipped transistor; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$ 

# 12. Package outline



50 V, 100 mA NPN resistor-equipped transistor; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$ 

# 13. Soldering



50 V, 100 mA NPN resistor-equipped transistor; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$ 

# 14. Revision history

## Table 9. Revision history

Table 3. Revision mistory					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
PDTC124ET v.9	20221013	Product data sheet	-	PDTC124E_SER v.8	
Modification:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Product changed to non automotive. Please refer to the automotive product(s) with -Q.</li> <li>Family data sheet reduced to single type data sheet.</li> <li>Packing information removed.</li> </ul>				
PDTC124E_SER v.8	20111128	Product data sheet	-	PDTC124E_SERIES v.7	
PDTC124E_SERIES v.7	20040817	Product data sheet	-	PDTC124E_SERIES v.6	
PDTC124E_SERIES v.6	20030414	Product specification	-	-	

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### 50 V, 100 mA NPN resistor-equipped transistor; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$

# 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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